### MC1496/MC1596

#### DESCRIPTION

The MC1496 is a monolithic double-balanced modulator/demodulator designed for use where the output voltage is a product of an input voltage (signal) and a switched function (carrier). The MC1596 will operate over the full military temperature range of -55 to +125°C. The MC1496 is intended for applications within the range of 0 to +70°C.

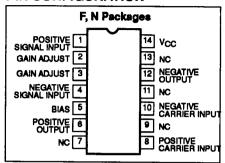
### **FEATURES**

- Excellent carrier suppression 65dB typ @ 0.5MHz 50dB typ @ 10MHz
- Adjustable gain and signal handling
- Balanced inputs and outputs
- High common-mode rejection—85dB typ

#### **APPLICATIONS**

- Suppressed carrier and amplitude modulation
- Synchronous detection
- FM detection
- Phase detection
- Sampling
- Single sideband
- Frequency doubling

### **PIN CONFIGURATION**



### **ORDERING INFORMATION**

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #		
14-Pin Cerdip	0 to +70°C	MC1496F			
14-Pin Plastic	0 to +70°C	MC1496N	0405		
14-Pin Cerdip	-55 to +125°C	MC1596F	0581		
14-Pin Plastic	-55 to +125°C	MC1596N	0405		

### **ABSOLUTE MAXIMUM RATINGS**

SYMBOL	PARAMETER	RATING		
	Applied voltage	30	V	
V <sub>8</sub> -V <sub>10</sub>	Differential input signal	±5.0	V	
V <sub>4</sub> -V <sub>1</sub>	Differential input signal	(5±l <sub>5</sub> R <sub>e</sub> )	V	
V <sub>2</sub> -V <sub>1</sub> , V <sub>3</sub> -V <sub>4</sub>	Input signal	5.0	V	
l <sub>5</sub>	Bias current	10	mA	
P <sub>D</sub>	Maximum power dissipation, T <sub>A</sub> =25°C (still-air) <sup>1</sup> F package N package	1190 1420	mW mW	
T <sub>A</sub>	Operating temperature range MC1496 MC1596	0 to +70 -55 to +125	°C	
T <sub>STG</sub>	Storage temperature range	-65 to +150	°C	

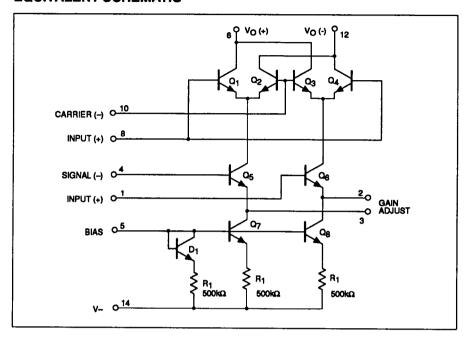
#### NOTES:

1. Derate above 25°C, at the following rates:

F package at 9.5mW/°C N package at 11.4mW/°C

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### **EQUIVALENT SCHEMATIC**



### DC ELECTRICAL CHARACTERISTICS

 $V_{CC}\text{=+}12V_{DC};\ V_{CC}\text{=-}8.0V_{DC};\ I5\text{=}1.0\text{mADC};\ R_{L}\text{=}3.9\text{k}\Omega;\ R_{E}\text{=}1.0\text{k}\Omega;\ T_{A}\text{=-}25^{\circ}\text{C},\ unless\ otherwise\ specified.}$ 

SYMBOL	PARAMETER	TEST CONDITIONS	MC1596			MC1496			UNIT
			Min	Тур	Max	Min	Тур	Max	
R <sub>IP</sub> C <sub>IP</sub>	Single-ended input impedance Parallel input resistance Parallel input capacitance	Signal port, f=5.0MHz		200 2.0			200 2.0		kΩ pF
R <sub>OP</sub> C <sub>OP</sub>	Single-ended output impedance Parallel output resistance Parallel output capacitance	f=10MHz		40 5.0			40 5.0		kΩ pF
I <sub>BS</sub>	Input bias current I <sub>BS</sub> = I <sub>BC</sub> =			12 12	25 25		12 12	30 30	μ <b>Α</b> μ <b>Α</b>
l <sub>ios</sub>	Input offset current  I <sub>IOS</sub> =I <sub>1</sub> -I <sub>4</sub> I <sub>IOC</sub> =I <sub>8</sub> -I <sub>10</sub>			0.7 0.7	5.0 5.0		0.7 0.7	7.0 7.0	μ <b>Α</b> μ <b>Α</b>
Tcho	Average temperature coefficient of input offset current Output offset current			2.0			2.0		nA/°C
l∞	l <sub>6</sub> -l <sub>12</sub>			14	50		15	80	μΑ
T <sub>cloo</sub> V <sub>o</sub>	Average temperature coefficient of output offset current Common-mode quiescent output voltage (Pin 6 or Pin 12)			90 8.0			90 8.0		nA/°C V <sub>DC</sub>
l <sub>D+</sub> l <sub>D-</sub>	Power supply current I <sub>6</sub> +I <sub>12</sub> I <sub>14</sub>			2.0	3.0 4.0		2.0 3.0	4.0 5.0	mA <sub>DC</sub>
P <sub>D</sub>	DC power dissipation	<u> </u>		33			33	- · · ·	mW

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### **AC ELECTRICAL CHARACTERISTICS**

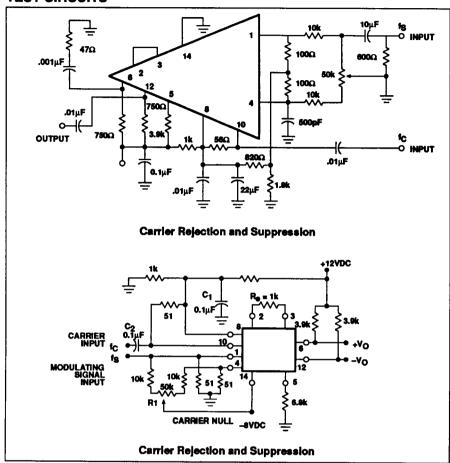
 $V_{CC}$ =+12 $_{DC}$ ;  $V_{CC}$ =-9.0 $V_{DC}$ ;  $I_{S}$ =1.0mA $_{DC}$ ;  $R_{L}$ =3.9k $\Omega$ ;  $R_{E}$ =1.0k $\Omega$ ;  $T_{A}$ =+25°C unless otherwise specified.

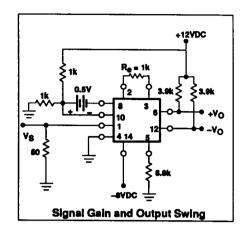
SYMBOL	PARAMETER	TEST CONDITIONS	MC1596			MC1496			UNIT
			Min	Тур	Max	Min	Тур	Max	1
V <sub>CFT</sub>	Carrier feedthrough	V <sub>C</sub> =60mV <sub>RMS</sub> sinewave and offset adjusted to zero							
		f <sub>C</sub> =1.0kHz		40			40		μV <sub>RMS</sub>
		f <sub>C</sub> =10MHz		140			140		
		V <sub>C</sub> =300mV <sub>P-P</sub> squarewave:							
		Offset adjusted to zero f <sub>C</sub> =1.0kHz		0.04	0.2	1	0.04	0.4	mV <sub>RMS</sub>
		Offset not adjusted f <sub>C</sub> =1.0kHz		20	100		20	200	
V <sub>CS</sub>	Carrier suppressions	f <sub>S</sub> =10kHz, 300mV <sub>RMS</sub> sinewave						1	
		f <sub>C</sub> =500kHz, 60mV <sub>RMS</sub> sinewave	50	65		40	65		dB
	<u> </u>	f <sub>C</sub> =10MHz, 60mV <sub>RMS</sub> sinewave		50			50	ŀ	
BW <sub>3dB</sub>	Transadmittance bandwidth	Carrier input port, V <sub>C</sub> =60mV <sub>RMS</sub>		300			300		MHz
	(Magnitude) (R <sub>L</sub> =50Ω)	sinewave f <sub>S</sub> =1.0kHz,							
		300mV <sub>RMS</sub> sinewave							
		Signal input port, V <sub>S</sub> =300mV <sub>RMS</sub>		80			80		MHz
		sinewave $ V_C  = 0.5V_{DC}$	ľ						
A <sub>VS</sub>	Signal gain	V <sub>S</sub> =100mV <sub>RMS</sub> ; f=1.0kHz	2.5	3.5		2.5	3.5		V/V
		V <sub>C</sub>   = 0.5V <sub>DC</sub>							
CMV	Common-mode input swing	Signal port, f <sub>S</sub> =1.0kHz		5.0			5.0		V <sub>P-P</sub>
A <sub>CM</sub>	Common-mode gain	Signal port, f <sub>S</sub> =1.0kHz		-85			-85		dB
		V <sub>C</sub>   = 0.5V <sub>DC</sub>							
DV <sub>OUT</sub>	Differential output voltage swing capability			8.0			8.0		V <sub>P-P</sub>

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### **TEST CIRCUITS**





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